

MJE13007-XS

NPN SILICON TRANSISTOR

NPN BIPOLAR POWER TRANSISTOR FOR SWITCHING POWER SUPPLY APPLICATIONS

DESCRIPTION

The UTC **MJE13007-XS** is designed for high-voltage, high-speed power switching inductive circuits where fall time is critical. It is particularly suited for 115 and 220 V switch mode applications.

■ FEATURES

* V_{CEO(SUS)} 400V

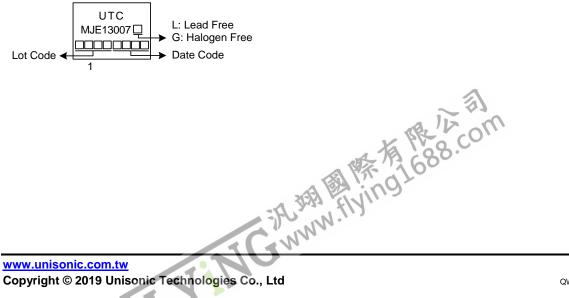
* 700V Blocking Capability

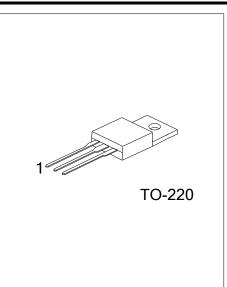
ORDERING INFORMATION

Ordering	Dookogo	Pin Assignment			Decking	
Lead Free	Halogen Free	Package	1	2	3	Packing
MJE13007L-XS-TA3-T	MJE13007G-XS-TA3-T	TO-220	В	С	Е	Tube
Note: Pin Assignment: B: Bas	e C: Collector E: Emitte	er				

MJE13007G-XS- <u>TA3-T</u>	
(1)Packing Type	(1) T: Tube
(2)Package Type	(2) TA3: TO-220
(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING





■ ABSOLUTE MAXIMUM RATING

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-Emitter Sustaining Voltage		V _{CEO}	400	V	
Collector-Emitter Breakdown Voltage		V _{CBO}	700	V	
Collector-Emitter Voltage		V _{CES}	700	V	
Emitter-Base Voltage		V _{EBO}	9.0	V	
Collector Current	Continuous	Ιc	5	А	
	Peak (1)	I _{CM}	10	А	
Power Dissipation ($T_c = 25^{\circ}C$)		P _D	80	W	
Junction Temperature		ΤJ	+150	°C	
Storage Temperature		T _{STG}	-55 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

THERMAL DATA

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	θ_{JA}	62.5	°C/W
Junction to Case	θ _{JC}	1.56	°C/W

Note: 1. Pulse Test: Pulse Width = 5.0 ms, Duty Cycle \leq 10%.

Measurement made with thermocouple contacting the bottom insulated mounting surface of the package (in a location beneath the die), the device mounted on a heatsink with thermal grease applied at a mounting torque of 6 to 8•lbs.

ELECTRICAL CHARACTERISTICS (T_c=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
Collector-Emitter Sustaining Voltage	V _{CEO(SUS)}	I _C =10mA, I _B =0	400			V	
Collector Cutoff Current	I _{CBO}	V _{CES} =700V			0.1	mA	
		V _{CES} =700V, T _C =125°C			1.0	mA	
Emitter Cutoff Current	I _{EBO}	$V_{EB}=9.0V, I_{C}=0$			100	μA	
DC Current Gain	h _{FE1}	I _C =2.0A, V _{CE} =5.0V	8.0		40		
	h _{FE2}	I _C =5.0A, V _{CE} =5.0V	5.0		30		
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	I _C =5.0A, I _B =1.0A			2.0	V	
Base-Emitter Saturation Voltage	V _{BE(SAT)}	I _C =5.0A, I _B =1.0A			1.6	V	
Output Capacitance	C _{OB}	V _{CB} =10V, I _E =0, f=0.1MHz		57		рF	
RESISTIVE LOAD (TABLE 1)							
Delay Time	t _D			0.025	0.1	μs	
Rise Time	t _R	$V_{\rm CC} = 125V, I_{\rm C} = 5.0A,$		0.5	1.5	μs	
Storage Time	t _S	$I_{B1}=I_{B2}=1.0A$, $t_{P}=25\mu s$,		1.8	3.0	μs	
Fall Time	t _F	Duty Cycle≤1.0%		0.23	0.7	μs	

Note: Pulse Test: Pulse Width≤300µs, Duty Cycle≤2.0%

MJE13007-XS

40

35

30

25

20

15

10

5

0

6

5

4

2

1

0 0.01

0.1

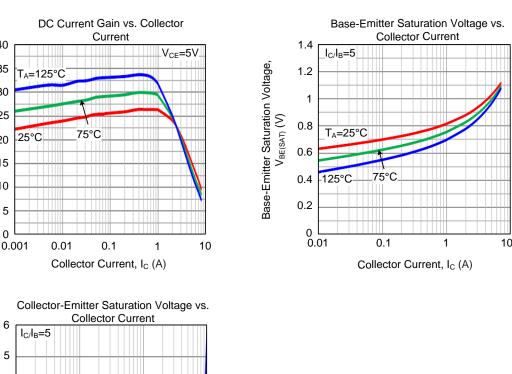
Collector Current, I_C (A)

Collector-Emitter Saturation Voltage,

V_{CE(SAT)} (V) 3

DC Current Gain, h_{FE}

TYPICAL CHARACTERISTICS



T_A=125°C

75°C

10

1

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. UTC reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.



3 of 3 QW-R223-028.B